Low Light Rejection Phototransistor

FEATURES

DESCRIPTION

Distinguising Feature:

- T-1 plastic package
- Low light level immunity
- 20° (nominal) acceptance angle
- Mechanically and spectrally matched to SEP8505 and SEP8705 infrared emitting diodes

The SDP8475 is an NPN silicon phototransistor which

of this device in a clear T- 1 plastic package assures superior optical centerline performance compared to

provide a simple method of polarity identification.

internal base- emitter shunt resistance. Transfer molding

other molding processes. Lead lengths are staggered to

This device incorporates all of the desired features of a

standard phototransistor with the advantage of low light

immunity. The phototransistor switching occurs when

the incident light increases above the threshold (knee

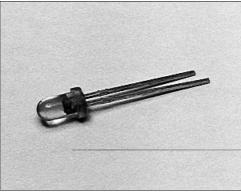
point). When the light level exceeds the knee point of

rejection phototransistor as compared to a standard

Ideally suited for use in applications which require ambient light rejection, or in transmissive applications where the interrupter media is semi- transparent to infrared energy. This device also provides high contrast ratio in reflective applications where unwanted background reflection is a possibility.

phototransistor with similar sensitivity. Typical Application Uses:

the device, it will function as a standard phototransistor. Chart A illustrates the light current output of the low light

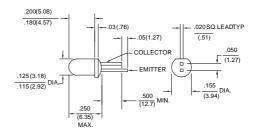


INFRA-22.TIF

OUTLINE DIMENSIONS in inches (mm)

Tolerance

3 plc decimals ±0.005(0.12) 2 plc decimals ±0.020(0.51)



DIM_100.ds4

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Low Light Rejection Phototransistor

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current Slope (1) (2)	I∟ Slope				mA/mW/cm ²	V _{CE} =5 V
SDP8475-201		4.0		14.0		H ₁ = 0.5 mW/cm ²
						H ₂ = 0.25 mW/cm ²
Knee Point (3)			0.125		mW/cm ²	V _{CE} =5 V
Collector Dark Current	ICEO			100	nA	H=0 mW/cm², V _{CE} =15 V
Collector-Emitter Breakdown Voltage	V(BR)CEO	30			V	Ic=100 μA
Collector-Emitter Saturation Voltage	VCE(SAT)			0.4	V	lc=l∟/8 H=0.25mW/cm²
Reverse Current	IR			40	mA	V _{CE} =-5.0 V
Angular Response (4)	Ø		20		degr.	IF=Constant
Rise And Fall Time	tr, tf		15		μs	Vcc=5 V, I∟=1 mA
						RL=1000 Ω

Notes

The Slope is calculated with the following equation: (I_{L1} (@ H₁) - I_{L2} (@ H₂)) / (H₁ - H₂).
The radiation source is an IRED with a peak wavelength of 935 nm.
Knee Point is defined as being the source irradiance required to increase I_L to 50 μA.
Angular response is defined as the total included angle between the half sensitivity points.

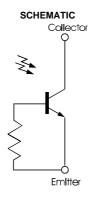
ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Collector-Emitter Voltage	30 V
Power Dissipation	70 mW (1)
Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

Notes

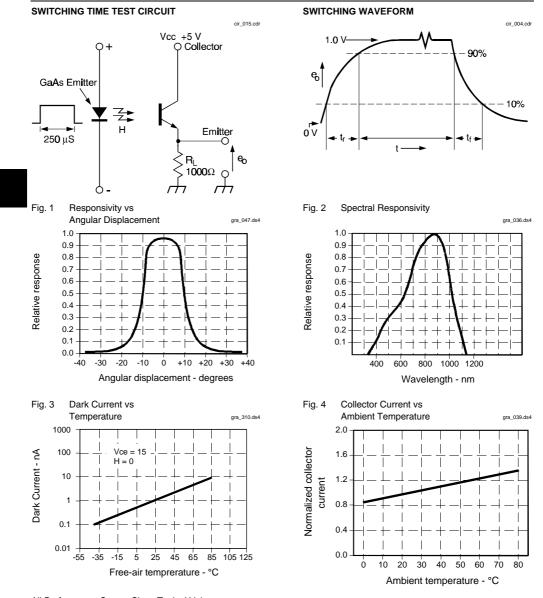
1. Derate linearly from 25°C free-air temperature at the rate of 0.18 mW/°C.



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All Performance Curves Show Typical Values

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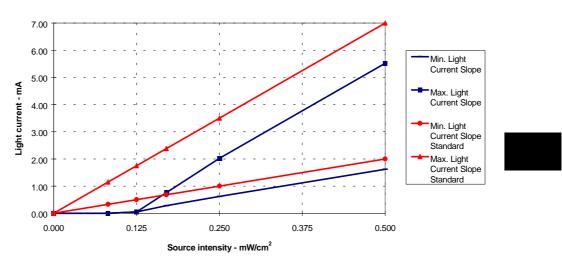


Chart A. Low Light Rejection Phototransistor vs. Standard Phototransistor

Designing with the Low Light Rejection Phototransistor:

The Low Light Rejection detector is tested at different incident light levels to determine adherence to the specified knee point and light current slope. This method assures proper functionality vs. standard phototransistors, and guarantees required light current output.

The light current slope is the change in light current output at two given source irradiances divided by the change in the two source irradiances.

(Formula # 1)

 I_{L} Slope = $[I_{L_{1}} (@ H_{1}) - I_{L_{2}} (@ H_{2})] / [H_{1} - H_{2}]$

Where

- I slope is the light current slope in mA/mW/cm²
- I is the light current output in mA
- H is the source intensity in mW/cm²

Chart A shows the specified limits of light current slope for the low light rejection phototransistor which begins its slope at the typical knee point, 0.125mW/cm². To make a clear distinction between this device and a standard phototransistor, light current slopes for high and low sensitivity standard phototransistors are also shown. Note that for phototransistors of the same gain, the slopes of the two products are parallel.

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(Formula # 2)

 $I_{\perp} = I_{\perp} \text{ slope}_{\text{MIN.}} * (H_{\text{A}} - H_{\text{KP}})$

Where:

- I_L is the light current output in mA
- I slope is the minimum limit on the light current slope (i.e. 4.0mA/mW/cm²)
- H_A is the source light incident on the detector for the application
- $H_{_{\mu\nu}}$ is the specified level of source light incident on the detector at the typical knee point (i.e. 0.125 mW/cm²)

Example :

To design a transmissive sensor with two of Honeywell's standard components, the SEP8505-002 and the SDP8475-201, it is first necessary to determine the irradiance level in mW/cm² that will be incident on the detector. The application conditions are the following:

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SDP8475-201 Low Light Rejection Phototransistor

Supply voltage = 5V Distance between emitter and detector = 0.4 in. (10.16mm) IRED drive current = 20mA

The SEP8505-002 gives 1.0mW/cm² min. to 4.0mW/cm² max. under the above conditions. To obtain minimum light current output, use the minimum irradiance limit.

 $\begin{array}{l} \mbox{Light current output} = \mbox{I}_{L} \mbox{slope}_{\mbox{\tiny MIN.}} ^{*} (\mbox{H}_{A} - \mbox{H}_{\mbox{\tiny KP}}) \\ \mbox{Light current output} = \mbox{4.0 mA/mW/cm}^{2} \mbox{min.} ^{*} (\mbox{1.0 mW/cm}^{2} \mbox{min.} ^{*} \mbox{min.} \\ \mbox{mW/cm}^{2} \mbox{min.} - \mbox{0.125 mW/cm}^{2}) = \mbox{3.5mA min.} \end{array}$

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